



NSI1400D

# High Reliability Reinforced Isolated Amplifier

## Datasheet (EN)1.0

### Product Overview

NSI1400 is a high-performance isolated amplifier with output separated from input based on the NOVOSENSE capacitive isolation technology. The device has a linear differential input signal range of  $\pm 250\text{mV}$  ( $\pm 320\text{mV}$  full-scale). The differential input is ideally suited to shunt resistor-based current sensing in high voltage applications where isolation is required.

The device has a fixed gain of 8.2 and provides a differential analog output. The low offset and gain drift ensure the accuracy over the entire temperature range. High common-mode transient immunity ensures that the device is able to provide accurate and reliable measurements even in the presence of high-power switching such as in motor control applications.

The fail-safe functions including input common-mode overvoltage detection and missing VDD1 detection simplify system-level design and diagnostics.

### Key Features

- Up to  $5000\text{V}_{\text{rms}}$  Insulation voltage
- $\pm 250\text{mV}$  linear Input Voltage Range
- Fixed Gain of 8.2
- Excellent DC Performance:
  - Offset Error:  $\pm 0.5\text{mV}$  (Max)
  - Offset Error Drift:  $\pm 4\mu\text{V}/^{\circ}\text{C}$  (Max)
  - Gain Error:  $\pm 0.3\%$  (Max)
  - Gain Error Drift:  $\pm 30\text{ppm}/^{\circ}\text{C}$  (Max)
  - Nonlinearity:  $\pm 0.05\%$  (Max)
  - Nonlinearity Drift:  $\pm 1\text{ppm}/^{\circ}\text{C}$  (Typ)
- SNR: 72dB (Typ, BW=100kHz)
- Wide bandwidth: 220kHz (Typ)
- High CMTI: 125kV/ $\mu\text{s}$  (Typ)
- System-Level Diagnostic Features:
  - VDD1 monitoring

- Input common-mode overvoltage detection
- Operation Temperature:  $-40^{\circ}\text{C} \sim 125^{\circ}\text{C}$
- RoHS-Compliant Packages:
  - SOP8(300mil), SOP8(150mil)

### Safety Regulatory Approvals

- UL recognition:
  - SOW8:  $5000\text{V}_{\text{rms}}$  for 1 minute per UL1577
  - SOP8:  $3000\text{V}_{\text{rms}}$  for 1 minute per UL1577
- CQC certification per GB4943.1
- CSA component notice 5A
- DIN EN IEC 60747-17 (VDE 0884-17)

### Applications

- Shunt current monitoring
- Motor Drives
- Uninterruptible Power Suppliers
- Solar Inverters

### Device Information

Part Number	Package	Body Size
NSI1400D-DSWVR	SOP8(300mil)	5.85mm $\times$ 7.50mm
NSI1400D-DSPR	SOP8(150mil)	4.90mm $\times$ 3.90mm

### Functional Block Diagrams

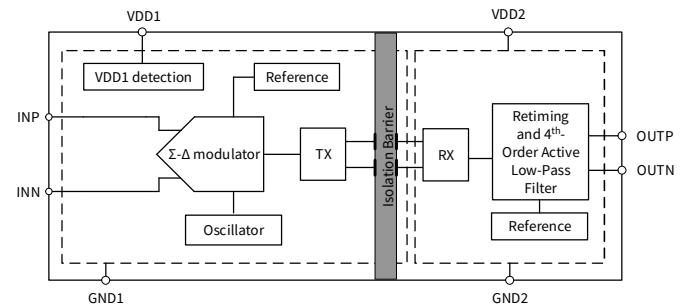


Figure 1. NSI1400D Block Diagram

## INDEX

<b>1. PIN CONFIGURATION AND FUNCTIONS.....</b>	<b>3</b>
<b>2. ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup> .....</b>	<b>4</b>
<b>3. ESD RATINGS<sup>(1)</sup>.....</b>	<b>4</b>
<b>4. RECOMMENDED OPERATING CONDITIONS.....</b>	<b>4</b>
<b>5. THERMAL INFORMATION.....</b>	<b>5</b>
<b>6. SPECIFICATIONS.....</b>	<b>5</b>
<b>6.1. ELECTRICAL CHARACTERISTICS.....</b>	<b>5</b>
<b>6.2. TYPICAL PERFORMANCE CHARACTERISTICS .....</b>	<b>7</b>
<b>6.3. PARAMETER MEASUREMENT INFORMATION .....</b>	<b>10</b>
<b>7. HIGH VOLTAGE FEATURE DESCRIPTION.....</b>	<b>10</b>
<b>7.1. INSULATION AND SAFETY RELATED SPECIFICATIONS .....</b>	<b>10</b>
<b>7.2. INSULATION CHARACTERISTICS.....</b>	<b>11</b>
<b>7.3. REGULATORY INFORMATION .....</b>	<b>12</b>
<b>8. FUNCTION DESCRIPTION .....</b>	<b>13</b>
<b>8.1. OVERVIEW .....</b>	<b>13</b>
<b>8.2. ANALOG INPUT .....</b>	<b>13</b>
<b>8.3. ANALOG OUTPUT .....</b>	<b>14</b>
<b>9. APPLICATION NOTE .....</b>	<b>15</b>
<b>9.1. TYPICAL APPLICATION CIRCUIT .....</b>	<b>15</b>
<b>9.2. SHUNT RESISTOR SELECTION .....</b>	<b>16</b>
<b>9.3. PCB LAYOUT .....</b>	<b>16</b>
<b>10. PACKAGE INFORMATION .....</b>	<b>17</b>
<b>11. ORDERING INFORMATION .....</b>	<b>19</b>
<b>12. DOCUMENTATION SUPPORT .....</b>	<b>19</b>
<b>13. TAPE AND REEL INFORMATION .....</b>	<b>20</b>
<b>14. REVISION HISTORY .....</b>	<b>22</b>

## 1. Pin Configuration and Functions

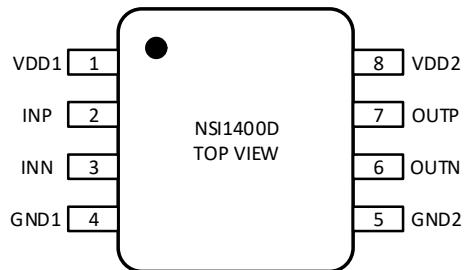


Figure 1.1 NSI1400D Package

Table 1.1 NSI1400 Pin Configuration and Description

<b>NSI1400D PIN NO.</b>	<b>SYMBOL</b>	<b>FUNCTION</b>
1	VDD1	Power supply for input side (3.0V to 5.5V)
2	INP	Positive analog input (±250mV recommended for NSI1400D)
3	INN	Negative analog input
4	GND1	Ground 1, the ground reference for input side
5	GND2	Ground 2, the ground reference for output side
6	OUTN	Negative output
7	OUTP	Positive output
8	VDD2	Power supply for output side (3.0V to 5.5V)

## 2. Absolute Maximum Ratings<sup>(1)</sup>

Parameters	Symbol	Min	Typ	Max	Unit
Power Supply Voltage <sup>(2)</sup>	VDD1, VDD2	-0.3		6.5	V
Input Voltage	INP, INN	GND1-6		VDD1+0.5	V
Output Voltage	OUTP, OUTN	GND2-0.5		VDD2+0.5	V
Input current per IO Pin	I <sub>in</sub>	-10		10	mA
Junction Temperature	T <sub>J</sub>	-40		150	°C
Storage Temperature	T <sub>STG</sub>	-55		150	°C

(1) The device cannot operate beyond the listed Absolute Maximum Ratings to prevent permanent device damage. The device is not fully functional if operating outside the Recommended Operating Conditions but within the Absolute Maximum Ratings. Long-time stress of the absolute maximum conditions may affect the device lifetime.

(2) VDD1 to GND1, VDD2 to GND2

## 3. ESD Ratings<sup>(1)</sup>

Parameters	Test condition	Value	Unit
Electrostatic discharge (ESD)	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(2)</sup>	±4000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(3)</sup>	±1000	V

(1) Though this device features proprietary protection circuitry, proper ESD precautions should be considered to avoid performance degradation or damage due to high energy ESD event. Charged devices and circuit boards may discharge without detection.

(2) Safe manufacturing requires 500-V HBM and standard ESD precautions, per JEDEC document JEP155.

(3) Safe manufacturing requires 250-V CDM and standard ESD precautions, per JEDEC document JEP157.

## 4. Recommended Operating Conditions

Parameters	Symbol	Min	Typ	Max	Unit
Input side Power Supply	VDD1	3.0	5.0	5.5	V
Output side Power Supply	VDD2	3.0	3.3	5.5	V
Differential input voltage before clipping output	V <sub>clipping</sub>		±320		mV
Linear differential input full scale voltage	V <sub>FSR</sub>	-250		250	mV
Operating common-mode input voltage	V <sub>CM</sub>	-0.16		2.6	V
Operating Ambient Temperature	T <sub>A</sub>	-40		125	°C

## 5. Thermal Information

Parameters	Symbol	SOP8(150mil)	SOP8(300mil)	Unit
Junction-to-ambient thermal resistance	R <sub>θJA</sub>	137.7	86	°C/W
Junction-to-case (top) thermal resistance	R <sub>θJC(top)</sub>	54.9	28	°C/W
Junction-to-board thermal resistance	R <sub>θJB</sub>	71.7	42	°C/W
Junction-to-top characterization parameter	Ψ <sub>JT</sub>	12	4	°C/W
Junction-to-board characterization parameter	Ψ <sub>JB</sub>	46	42	°C/W

## 6. Specifications

### 6.1. Electrical Characteristics

(VDD1 = 3.0V ~ 5.5V, VDD2 = 3.0V ~ 5.5V, INP = -250mV to +250mV, and INN = GND1 = 0V, T<sub>A</sub> = -40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 5V, VDD2 = 3.3V, T<sub>A</sub> = 25°C)

Parameters	Symbol	Min	Typ	Max	Unit	Comments
<b>Power Supply</b>						
Side1 Supply Voltage	VDD1	3.0	5.0	5.5	V	
Side2 Supply Voltage	VDD2	3.0	3.3	5.5	V	
Side1 Supply Current	IDD1	4.0	5.8	7.2	mA	
Side2 Supply Current	IDD2	4.0	5.1	6.3	mA	
VDD1 undervoltage detection threshold voltage	VDD1 <sub>UV</sub>	1.8	2.3	2.7	V	VDD1 falling
<b>Analog Input</b>						
Common-mode overvoltage detection level	V <sub>CMov</sub>		2.8		V	Detection level has a typical hysteresis of 110mV
Input offset voltage <sup>(1)</sup>	V <sub>os</sub>	-0.5	±0.1	0.5	mV	INP = INN = GND1, at T <sub>A</sub> = 25°C
Input offset drift <sup>(2)</sup>	TCV <sub>os</sub>	-4	1	4	µV/°C	
Common-mode rejection ratio	CMRR <sub>dc</sub>		-98		dB	INP = INN, f <sub>IN</sub> = 0 Hz, V <sub>CM min</sub> ≤ VIN ≤ V <sub>CM max</sub>
	CMRR <sub>ac</sub>		-95		dB	INP = INN, f <sub>IN</sub> = 10 kHz, V <sub>CM min</sub> ≤ VIN ≤ V <sub>CM max</sub>
Single-ended input resistance	R <sub>IN</sub>		29		kΩ	INN = GND1
Differential input resistance	R <sub>IND</sub>		29.5		kΩ	
Input capacitance	C <sub>i</sub>		12		pF	
Input bias current	I <sub>IB</sub>		-0.1		µA	INP = INN = GND1, I <sub>IB</sub> = (I <sub>IBP</sub> + I <sub>IBN</sub> ) / 2, at T <sub>A</sub> = 25°C
Input bias current drift <sup>(2)</sup>	TCI <sub>IB</sub>		±1		nA/°C	

Parameters	Symbol	Min	Typ	Max	Unit	Comments
<b>Analog Output</b>						
Nominal Gain			8.2		V/V	
Gain error <sup>(1)</sup>	E <sub>G</sub>	-0.3%	±0.05%	0.3%		at T <sub>A</sub> =25°C
Gain error thermal drift <sup>(1)(2)</sup>	TCE <sub>G</sub>	-30	±5	30	ppm/°C	
Nonlinearity <sup>(1)(3)</sup>		-0.05%	±0.01%	0.05%		at T <sub>A</sub> =25°C
Nonlinearity drift <sup>(1)(2)</sup>			±1		ppm/°C	
Total harmonic distortion <sup>(4)</sup>	THD		-90	-70	dB	V <sub>IN</sub> =500mVpp, f <sub>IN</sub> = 1kHz, BW = 10kHz
			-75		dB	V <sub>IN</sub> =500mVpp, f <sub>IN</sub> = 10kHz, BW = 100kHz
Output noise			360		µV <sub>RMS</sub>	INP = INN = GND1, BW = 100kHz
Signal to noise ratio	SNR	80	85		dB	V <sub>IN</sub> = 500mVpp, f <sub>IN</sub> = 1kHz, BW = 10kHz
			72		dB	V <sub>IN</sub> = 500mVpp, f <sub>IN</sub> = 10kHz, BW = 100kHz
Common-mode output voltage	V <sub>COut</sub>	1.38	1.45	1.49	V	For NSI1400D
Failsafe differential output voltage	V <sub>FAILSAFE</sub>		-2.6	-2.5	V	V <sub>CM</sub> >V <sub>CMov</sub> , or VDD1 missing
Output bandwidth	BW	175	220		kHz	
Power supply rejection ratio <sup>(5)</sup>	PSRR <sub>dc</sub>		-110		dB	PSRR vs VDD1, at DC
	PSRR <sub>ac</sub>		-100		dB	PSRR vs VDD1, 100mV and 10kHz ripple
	PSRR <sub>dc</sub>		-110		dB	PSRR vs VDD2, at DC
	PSRR <sub>ac</sub>		-90		dB	PSRR vs VDD2, 100mV and 10kHz ripple
Output resistance	R <sub>OUT</sub>		< 0.2		Ω	
Output current limit	I <sub>OUT</sub>		±13		mA	
Load capacitance	C <sub>LOAD</sub>		100		pF	
Common-mode transient immunity	CMTI	100	125		kV/µs	Common-mode transient immunity
<b>Timing</b>						
Rising time of OUTP, OUTN	t <sub>r</sub>		1.7		µs	
Falling time of OUTP, OUTN	t <sub>f</sub>		1.7		µs	
INP, INN to OUTP, OUTN signal delay (50% - 50%)	t <sub>PD</sub>		1.6	2.0	µs	C <sub>LOAD</sub> =15pF

Parameters	Symbol	Min	Typ	Max	Unit	Comments
Analog setting time	$t_{AS}$		0.5		ms	VDD1 step to 3.0 V with VDD2 $\geq$ 3.0 V, to OUTP, OUTN valid, 0.1% settling

- (1) The typical value includes one standard deviation (sigma) range under typical operating conditions.
- (2) The temperature drift is calculated with the whole temperature range (-40°C to 125°C).
- (3) Nonlinearity is defined as half of the peak-peak value of the deviation between the measuring point and the fitting curve divided by the full-scale range of the output voltage.
- (4) THD is defined as the ratio of the sum of the rms value of first nine higher harmonics to the amplitude of the fundamental.
- (5) Input referred.

## 6.2. Typical Performance Characteristics

Unless otherwise noted, test at VDD1 = 5V, VDD2 = 3.3V, INN=GND1=0V, INP = -250mV to 250mV,  $f_{IN} = 1\text{kHz}$ , BW = 10kHz.

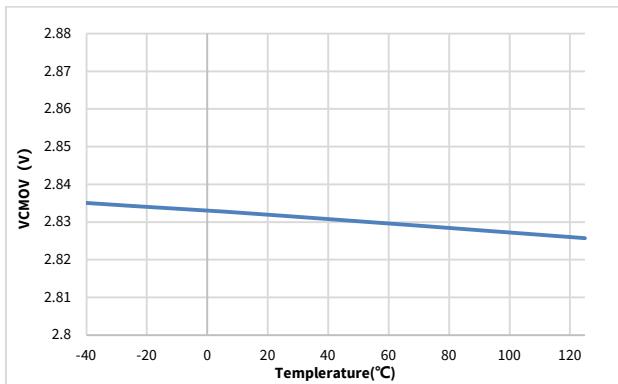


Figure 6.1 Common-Mode Overvoltage Detection Level vs Temperature

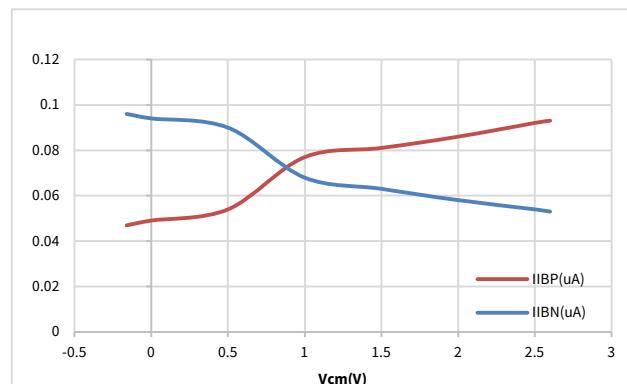


Figure 6.3 Input Bias Current vs Common-Mode Voltage

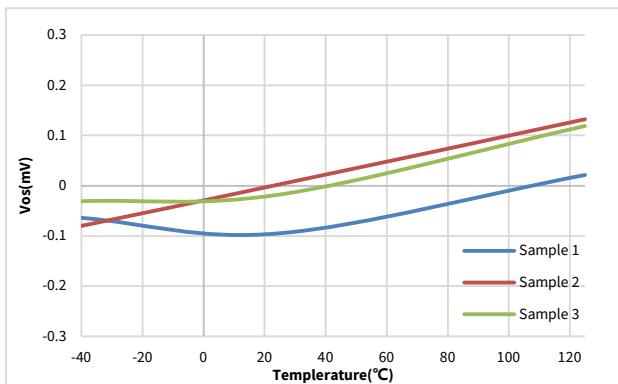


Figure 6.2 Input Offset Voltage vs Temperature

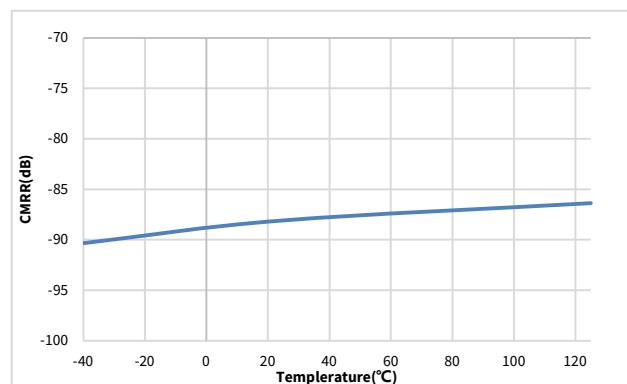


Figure 6.4 Common-Mode Rejection Ratio vs Temperature

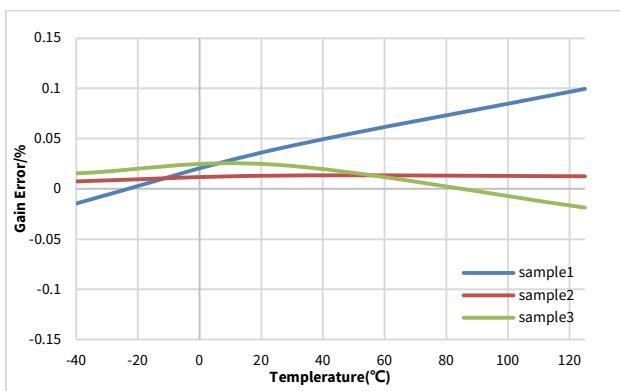


Figure 6.5 Gain Error vs Temperature

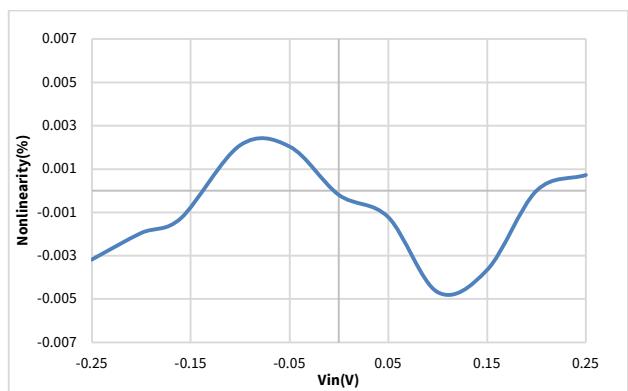


Figure 6.9 Nonlinearity vs Input Voltage

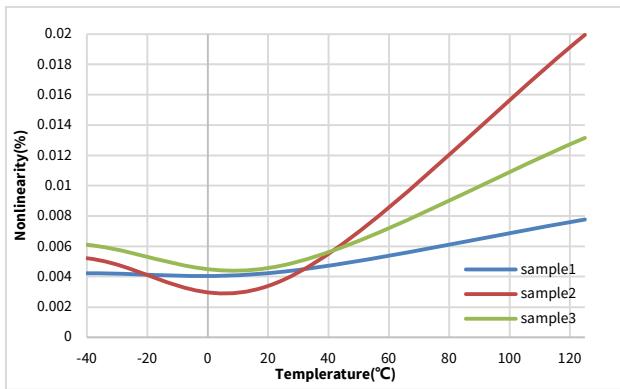


Figure 6.6 Nonlinearity vs Temperature

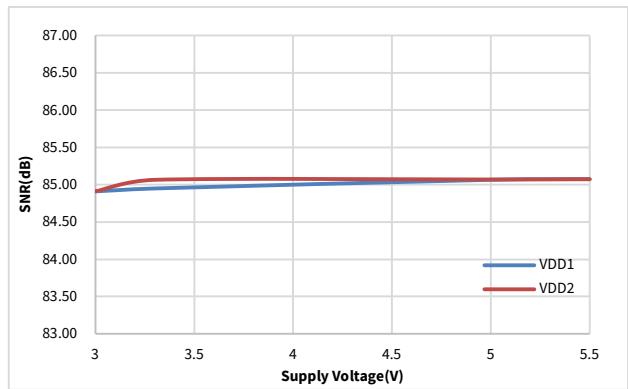


Figure 6.10 SNR vs Supply Voltage

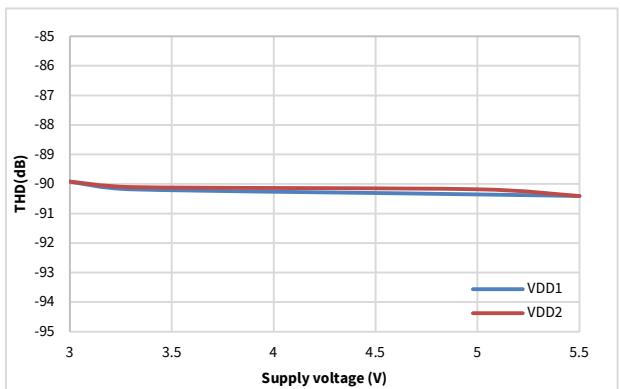


Figure 6.7 THD vs Supply Voltage

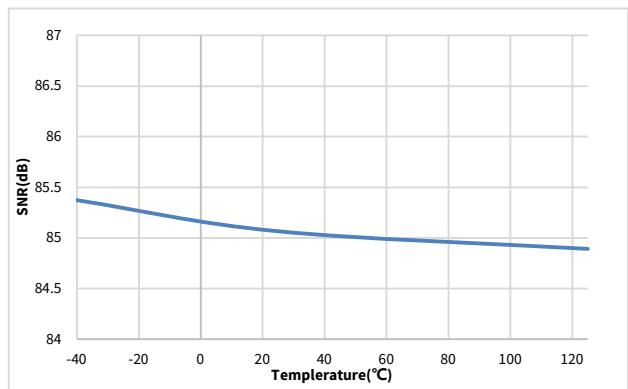


Figure 6.11 SNR vs Temperature

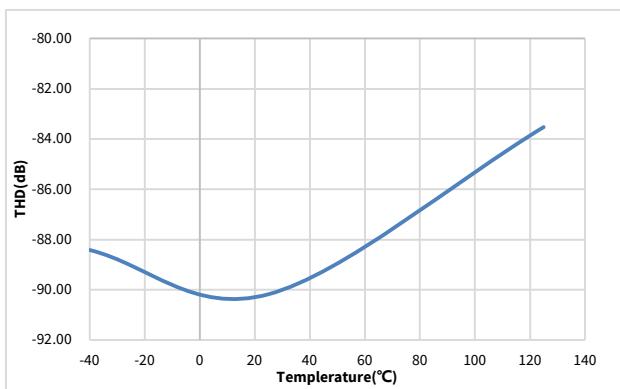


Figure 6.8 THD vs Temperature

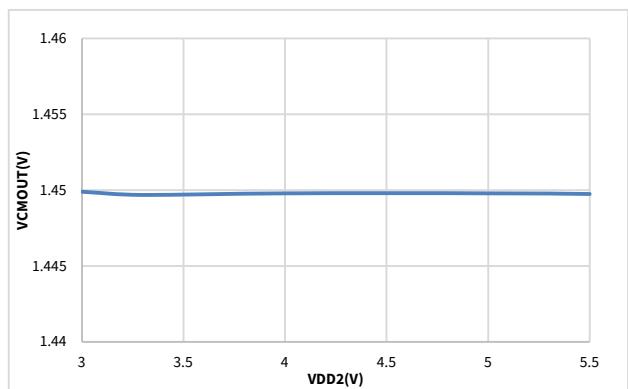


Figure 6.12 Output Common-Mode Voltage vs Side2 Supply Voltage

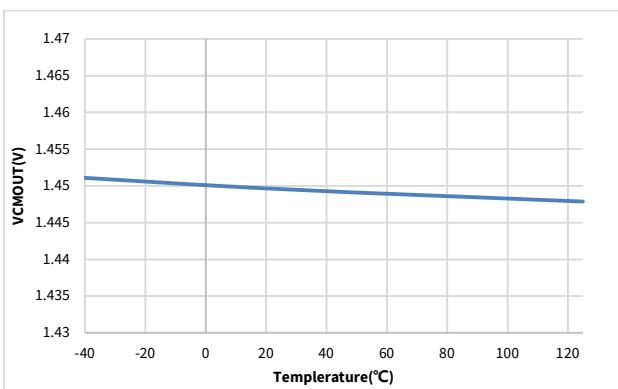


Figure 6.13 Output Common-Mode Voltage vs Temperature

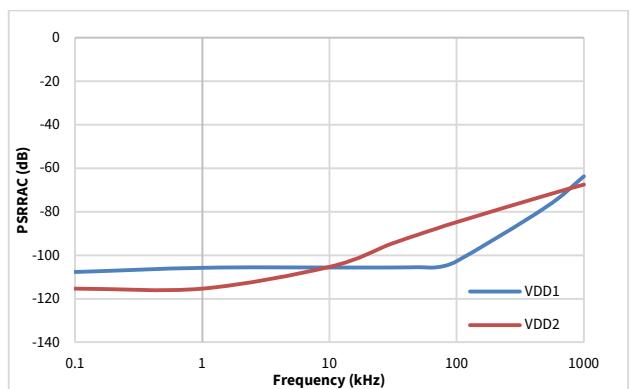


Figure 6.17 Power-Supply Rejection Ratio vs Ripple Frequency

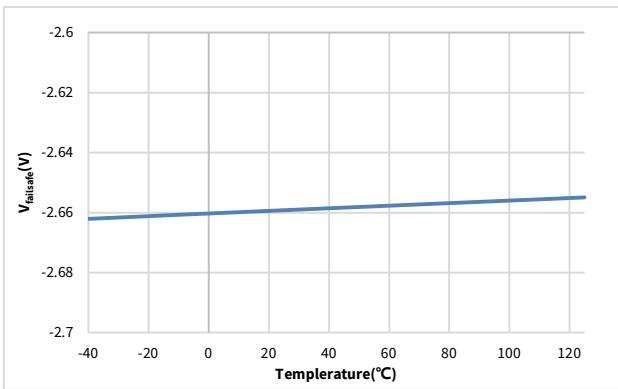


Figure 6.14 Fail-Safe Output Voltage vs Temperature

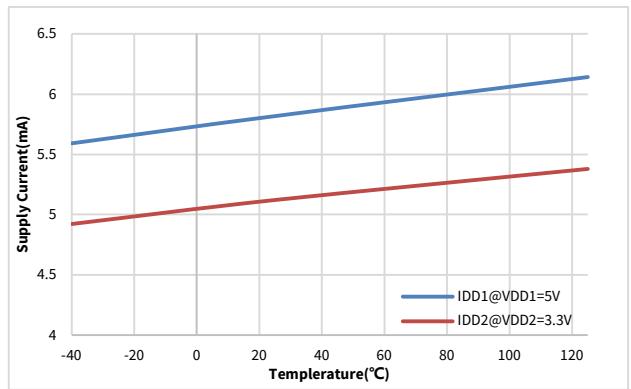


Figure 6.18 Supply Current vs Temperature

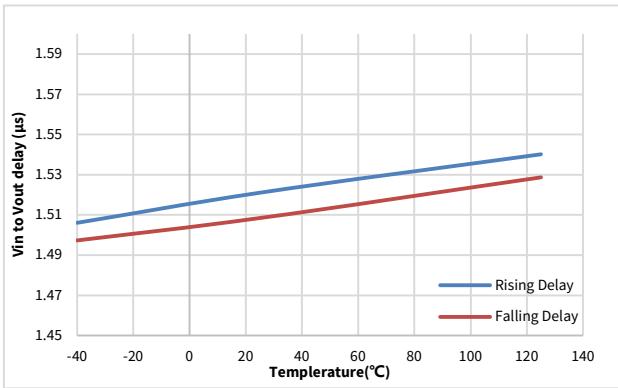


Figure 6.15 Vin to Vout Delay vs Temperature

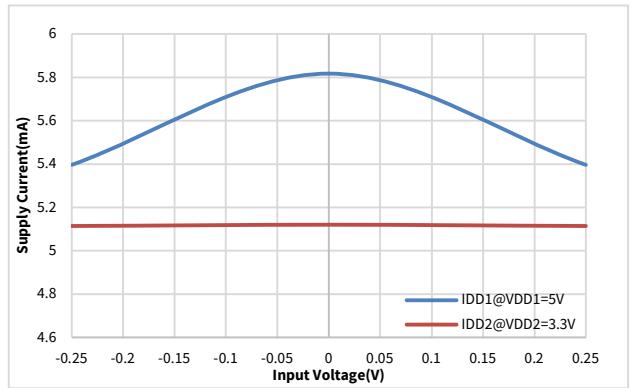


Figure 6.19 Supply Current vs Input Voltage

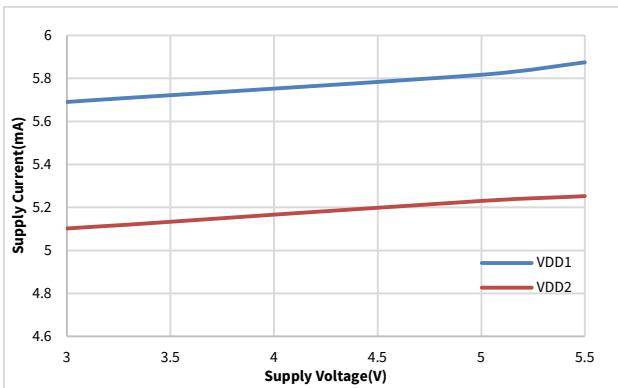


Figure 6.16 Supply Current vs Supply Voltage

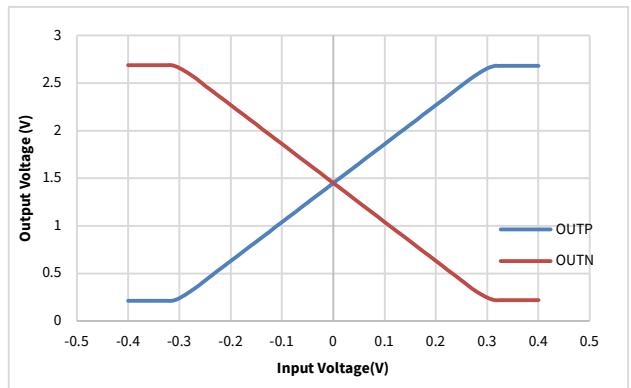


Figure 6.20 Output Voltage vs Input Voltage

### 6.3. Parameter Measurement Information

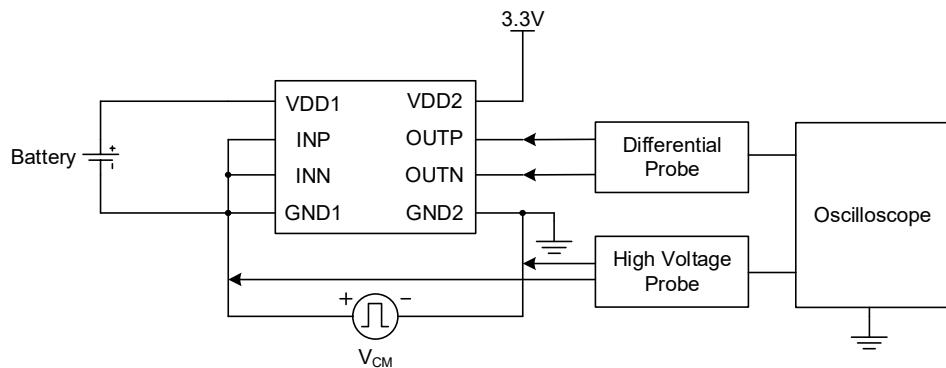


Figure 6.21 Common-Mode Transient Immunity Test Circuit

## 7. High Voltage Feature Description

### 7.1. Insulation and Safety Related Specifications

Parameters	Symbol	Value		Unit	Comments
		SOP8	SOW8		
Minimum External Clearance	CLR	4	8	mm	IEC 60664-1:2007
Minimum External Creepage	CPG	4	8	mm	IEC 60664-1:2007
Distance Through Insulation	DTI	28		μm	Distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>600		V	DIN EN 60112 (VDE 0303-11); IEC 60112
Material Group		I			IEC 60664-1

Description	Test Condition	Value	
		SOP8	SOW8
Overvoltage Category per IEC60664-1	For Rated Mains Voltage $\leq 150\text{Vrms}$	I to IV	I to IV
	For Rated Mains Voltage $\leq 300\text{Vrms}$	I to III	I to IV
	For Rated Mains Voltage $\leq 600\text{Vrms}$	I to II	I to IV
	For Rated Mains Voltage $\leq 1000\text{Vrms}$	I	I to III
Climatic Classification		40/125/21	
Pollution Degree per DIN VDE 0110		2	

## 7.2. Insulation Characteristics

Description	Test Condition	Symbol	Value		Unit
			SOP8	SOW8	
<b>DIN EN IEC 60747-17 (VDE 0884-17)</b>					
Maximum repetitive isolation voltage		$V_{IORM}$	990	2121	$V_{PEAK}$
Maximum working isolation voltage	AC Voltage	$V_{IOWM}$	700	1500	$V_{RMS}$
	DC Voltage		990	2121	$V_{DC}$
Apparent Charge	Method a, after Input/output safety test subgroup 2/3, $V_{ini}=V_{IOTM}$ , $t_{ini}=60\text{ s}$ , $V_{pd(m)}=1.2*V_{IORM}$ , $t_m=10\text{ s}$ .	$q_{pd}$	/	<5	$\text{pC}$
	Method a, after environmental tests subgroup 1, $V_{ini}=V_{IOTM}$ , $t_{ini}=60\text{ s}$ , $V_{pd(m)}=1.6*V_{IORM}$ , $t_m=10\text{ s}$				
	Method b, routine test (100% production) and preconditioning (type test); $V_{ini}=1.2*V_{IOTM}$ , $t_{ini}=1\text{ s}$ $V_{pd(m)}=1.875*V_{IORM}$ , $t_m=1\text{ s}$ (method b1) or $V_{pd(m)}=V_{ini}$ , $t_m=t_{ini}$ (method b2)				
Apparent Charge	Method a, after Input/output safety test subgroup 2/3, $V_{ini}=V_{IOTM}$ , $t_{ini}=60\text{ s}$ , $V_{pd(m)}=1.2*V_{IORM}$ , $t_m=10\text{ s}$ .	$q_{pd}$	<5	/	$\text{pC}$
	Method a, after environmental tests subgroup 1, $V_{ini}=V_{IOTM}$ , $t_{ini}=60\text{ s}$ , $V_{pd(m)}=1.3*V_{IORM}$ , $t_m=10\text{ s}$				
	Method b, routine test (100% production) and preconditioning (type test); $V_{ini}=1.2*V_{IOTM}$ , $t_{ini}=1\text{ s}$ $V_{pd(m)}=1.5*V_{IORM}$ , $t_m=1\text{ s}$ (method b1) or $V_{pd(m)}=V_{ini}$ , $t_m=t_{ini}$ (method b2)				
Maximum transient isolation voltage	$t = 60\text{ sec}$	$V_{IOTM}$	4242	8000	$V_{PEAK}$
Maximum impulse voltage	Tested in air, 1.2/50-us waveform per IEC62368-1	$V_{IMP}$	3000	6250	$V_{PEAK}$
Maximum Surge Isolation Voltage	Test method per IEC62368-1, 1.2/50us waveform, $V_{IOSM} \geq V_{IMP} \times 1.3$	$V_{IOSM}$	6000	10000	$V_{PEAK}$
Isolation resistance	$V_{IO} = 500\text{V}$ , $T_{amb}=25^\circ\text{C}$	$R_{IO}$	$>10^{12}$	$>10^{12}$	$\Omega$
	$V_{IO} = 500\text{V}$ , $100^\circ\text{C} \leq T_{amb} \leq 125^\circ\text{C}$	$R_{IO}$	$>10^{11}$	$>10^{11}$	$\Omega$
	$V_{IO} = 500\text{V}$ , $T_{amb}=T_s$	$R_{IO}$	$>10^9$	$>10^9$	$\Omega$
Isolation capacitance	$f = 1\text{MHz}$	$C_{IO}$	1.2	1.2	$\text{pF}$

<i>Description</i>	<i>Test Condition</i>	<i>Symbol</i>	<i>Value</i>		<i>Unit</i>
			<i>SOP8</i>	<i>SOW8</i>	
Safety total power dissipation	$V_I = 5.5V, T_J = 150 \text{ }^\circ\text{C}, T_A = 25 \text{ }^\circ\text{C}$	$P_s$	907	1453	mW
Safety input, output, or supply current	$\theta_{JA} = 137.7 \text{ }^\circ\text{C/W}$ for SOP8, $V_I = 5.5V, T_J = 150 \text{ }^\circ\text{C}, T_A = 25 \text{ }^\circ\text{C}$	$I_s$	165	/	mA
	$\theta_{JA} = 86 \text{ }^\circ\text{C/W}$ for SOW8, $V_I = 5.5V, T_J = 150 \text{ }^\circ\text{C}, T_A = 25 \text{ }^\circ\text{C}$		/	264	mA
Maximum safety temperature		$T_s$	150	150	$^\circ\text{C}$
<b>UL1577</b>					
Insulation voltage per UL	$V_{TEST} = V_{ISO}, t = 60 \text{ s}$ (qualification), $V_{TEST} = 1.2 \times V_{ISO}, t = 1 \text{ s}$ (100% production test)	$V_{ISO}$	3000	5000	$V_{RMS}$

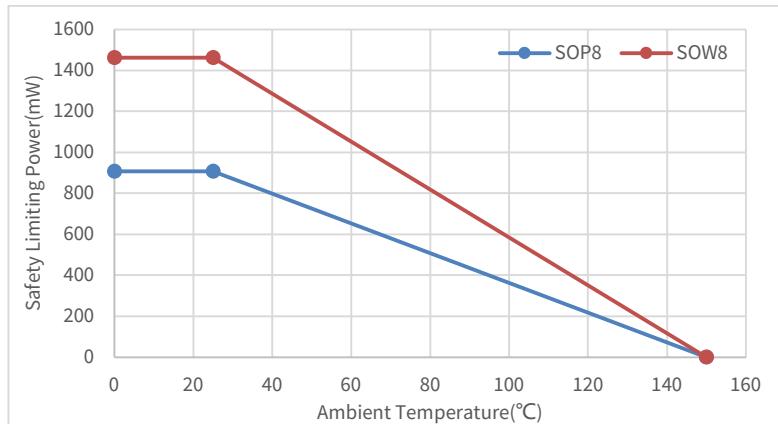


Figure 7.1 NSI1400 Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN EN IEC 60747-17

### 7.3. Regulatory Information

The NSI1400D-DSWVR are approved or pending approval by the organizations listed in table.

<b>UL</b>	<b>VDE</b>	<b>CQC</b>
UL 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	DIN EN IEC 60747-17 (VDE 0884-17) Certified by CQC11-471543-2012 GB4943.1-2011
Single Protection, $5000V_{rms}$ Isolation voltage	Single Protection, $5000V_{rms}$ Isolation voltage	Reinforce Insulation $V_{IORM}=2121V_{peak}$ $V_{IOTM}=8000V_{peak}$ $V_{IOSM}=10000V_{peak}$ Reinforced insulation
Certificate No.E500602	Certificate No.E500602	File (pending)

The NSI1400D-DSPR is approved or pending approval by the organizations listed in table.

UL	VDE	CQC
UL 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	DIN EN IEC 60747-17 (VDE 0884-17)
Single Protection, 3000V <sub>rms</sub> Isolation voltage	Single Protection, 3000V <sub>rms</sub> Isolation voltage	Basic Insulation V <sub>IORM</sub> =990Vpeak V <sub>IOTM</sub> =4242Vpeak V <sub>IOSM</sub> =6000Vpeak
Certificate No.E500602	Certificate No.E500602	File (pending)
		CQC20001264940

## 8. Function Description

### 8.1. Overview

The NSI1400 is a high-performance isolated amplifier that accepts fully-differential input. The fully-differential input is ideally suited to shunt current monitoring in high voltage applications where isolation is required. The analog input is continuously sampled by a second-order  $\Sigma\Delta$  modulator in the device. With the internal voltage reference and clock generator, the modulator converts the analog input signal to a digital bitstream. The output of the modulator is transferred by the drivers (called TX in the Functional Block Diagram) across the isolation barrier that separates the isolated input side and output side voltage. The received bitstream and clock are synchronized and processed, as shown in the Functional Block Diagram, by a fourth-order analog filter on the output side.

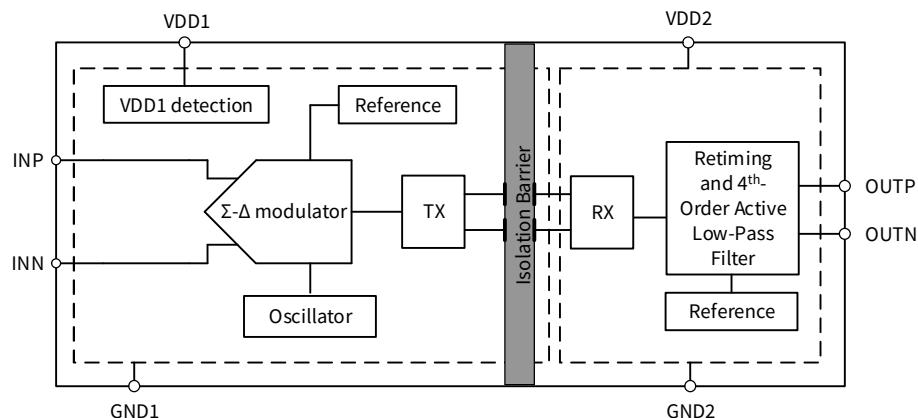


Figure 8.1 Function Block Diagram of NSI1400D

### 8.2. Analog Input

The analog input of the NSI1400 is a switched-capacitor circuit based on the second-order  $\Sigma\Delta$  modulator. The Equivalent circuit of analog input is shown in Figure 8.2. The internal capacitance  $C_{IND}$  is continuously charged and discharged through periodical switching action with the internal clock frequency  $f_{CLK}$  for input signal digitization. In the charging phase, the external input source must provide enough transient charge for the internal capacitance. To prevent transient voltage drop of  $C_{IND}$ , an external capacitor ( $C_{FLT}$  in Figure 8.1, also acting as filter capacitance) of more than 330pF should be placed as close as possible to the device as charge buffering, which ensures sensing accuracy.

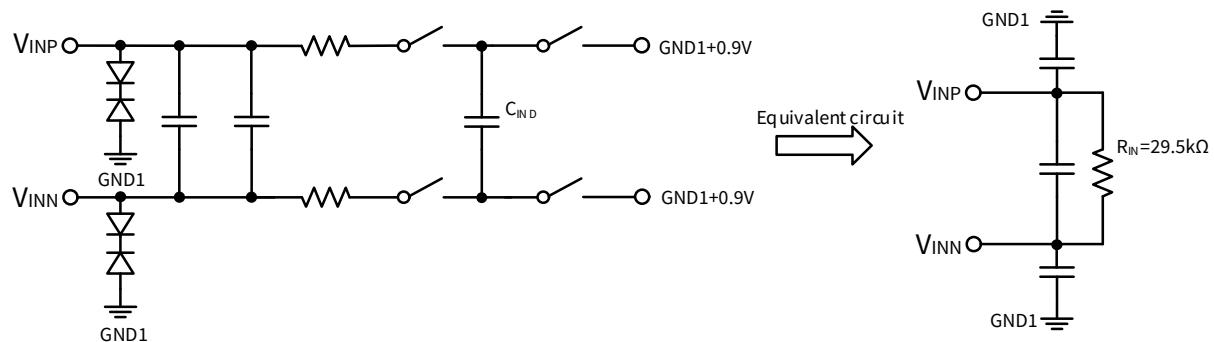


Figure 8.2 Equivalent Circuit of Analog Input

According to the equivalent circuit, the input resistance  $R_{IN}$  can be calculated as

$$R_{IND} = 1/(f_{CLK} * C_{IND})$$

There are two restrictions on the analog input signals ( $V_{INP}$  and  $V_{INN}$ ).

- If the input voltage exceeds the range GND1 – 6 V to VDD1 + 0.5 V, the input current must be limited to 10 mA because the device input electrostatic discharge (ESD) diodes turn on.
- The linearity and noise performance of the device are ensured only when the analog input voltage remains within the specified linear full-scale range (FSR) and within the specified common-mode input voltage range.

### 8.3. Analog Output

For linear input range, the analog output of NSI1400D has a fixed gain 8.2. If a full-scale input signal is applied to the NSI1400 ( $V_{IN} \geq V_{Clipping}$ ), the differential analog output ( $V_{OUTP} - V_{OUTN}$  for NSI1400D and  $V_{OUT} - REFIN$  for NSI1400S) will be clipped (typically, 2.45V for positive clipping and -2.45V for negative clipping).

For differential output version (NSI1400D), the differential output pins have a common-mode voltage of 1.45V (typ). The typical negative clipping output of NSI1400D is shown in Figure 8.3. The differential output  $V_{out}$  of the NSI1400D is expressed as:

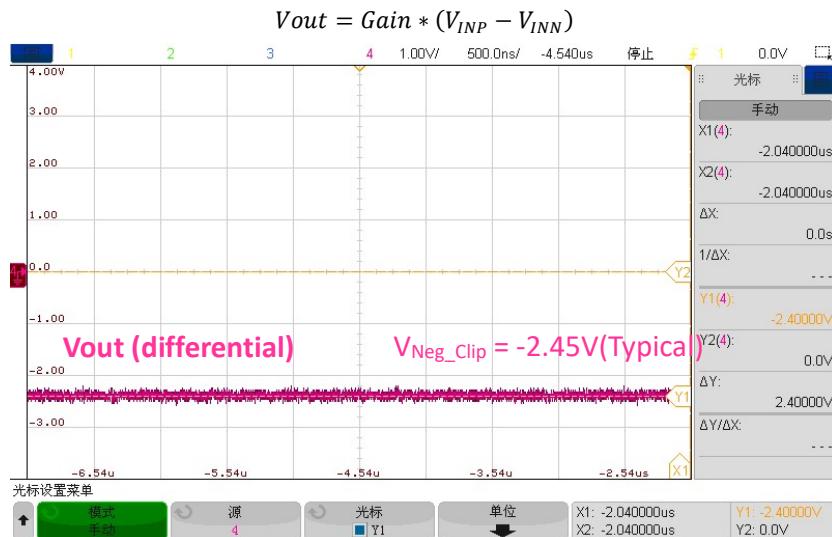


Figure 8.3 Typical negative clipping output of NSI1400

In addition, NSI1400 integrates some diagnostic measures and offers a fail-safe output to simplify system-level design. The fail-safe output is a negative differential output voltage that does not occur under normal device operation, and it will only be activated in following conditions:

- When the undervoltage of VDD1 is detected ( $VDD1 < VDD1_{UV}$ ).
- When the overvoltage of common-mode input voltage is detected ( $V_{CM} > V_{CMov}$ ).

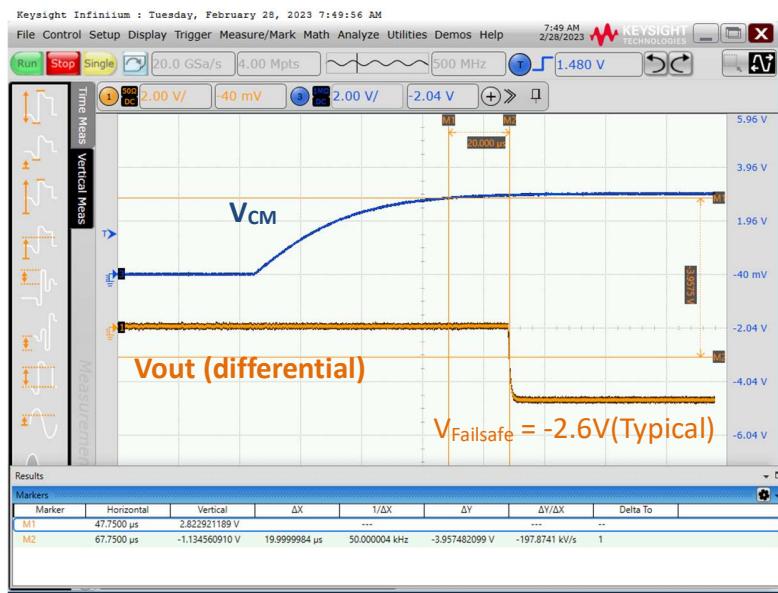
Figure 8.4 Typical Failsafe output when  $VDD1$  undervoltage

Figure 8.5 Typical Failsafe output when input common mode signal overvoltage

## 9. Application Note

### 9.1. Typical Application Circuit

NSI1400 is ideally suited to shunt resistor-based current sensing in high voltage applications such as motor drives. The typical application circuit is shown in Figure 9.1.

The voltage across the shunt resistor  $R_{sense}$  is applied to the differential input of NSI1400 through a RC filter ( $R_{FLT}$  and  $C_{FLT}$ ). The filter capacitance of more than 330pF placing as close as possible to the device must be added for charge buffering of the input switched-capacitor circuit (further details in 8.2 Analog Input) and better performance in high-noise applications.

The differential output of the isolated amplifier is converted to a single-ended analog output with an operational-amplifier-based circuit. Suggest to add  $>1\text{k}\Omega$  resistor on the OUTP and OUTN pin to prevent output over-current. An analog-to-digital converter usually receives the analog output and converts to digital signal for controller processing.

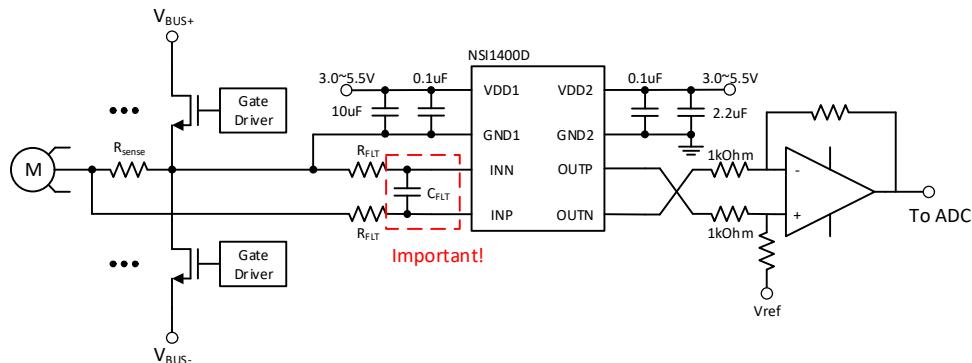


Figure 9.1 Typical application circuit in phase current sensing

## 9.2. Shunt Resistor Selection

Choosing a particular shunt resistor is usually a compromise between minimizing power dissipation and maximizing accuracy. Smaller sense resistor decreases power dissipation, while larger sense resistor can improve measure accuracy by utilizing the full input range of isolated amplifier.

There are two other factors should be considered when selecting the shunt resistor:

- The voltage-drop caused by the rated current range must not exceed the recommended linear input voltage range:  $V_{SHUNT} \leq FSR$ .
- The voltage-drop caused by the maximum allowed overcurrent must not exceed the input voltage that causes a clipping output:  $V_{SHUNT} \leq V_{Clipping}$ .

## 9.3. PCB Layout

There are some key guidelines or considerations for optimizing performance in PCB layout:

- Place the input filter capacitors as close as possible to the INP and INN pins for best performance.
- NSI1400 requires a 0.1 $\mu$ F bypass capacitor between VDD1 and GND1, VDD2 and GND2. The capacitor should be placed as close as possible to the VDD pin. If better filtering is required, an additional 1~10 $\mu$ F capacitor may be used.
- Kelvin rules is recommended for the connection between shunt resistor to NSI1400. Because of the Kelvin connection, any voltage drops across the trace and leads should have no impact on the measured voltage.
- Place the shunt resistor close to the INP and INN inputs and keep the layout of both connections symmetrical and run very close to each other to the input of the NSI1400. This minimizes the loop area of the connection and reduces the possibility of stray magnetic fields from interfering with the measured signal.

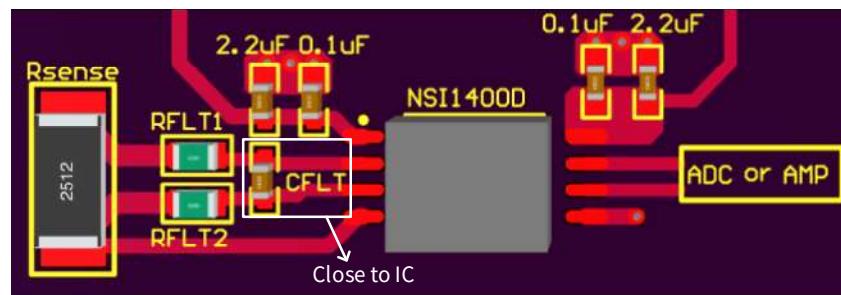


Figure 9.2 Typical application circuit in phase current sensing

## 10. Package Information

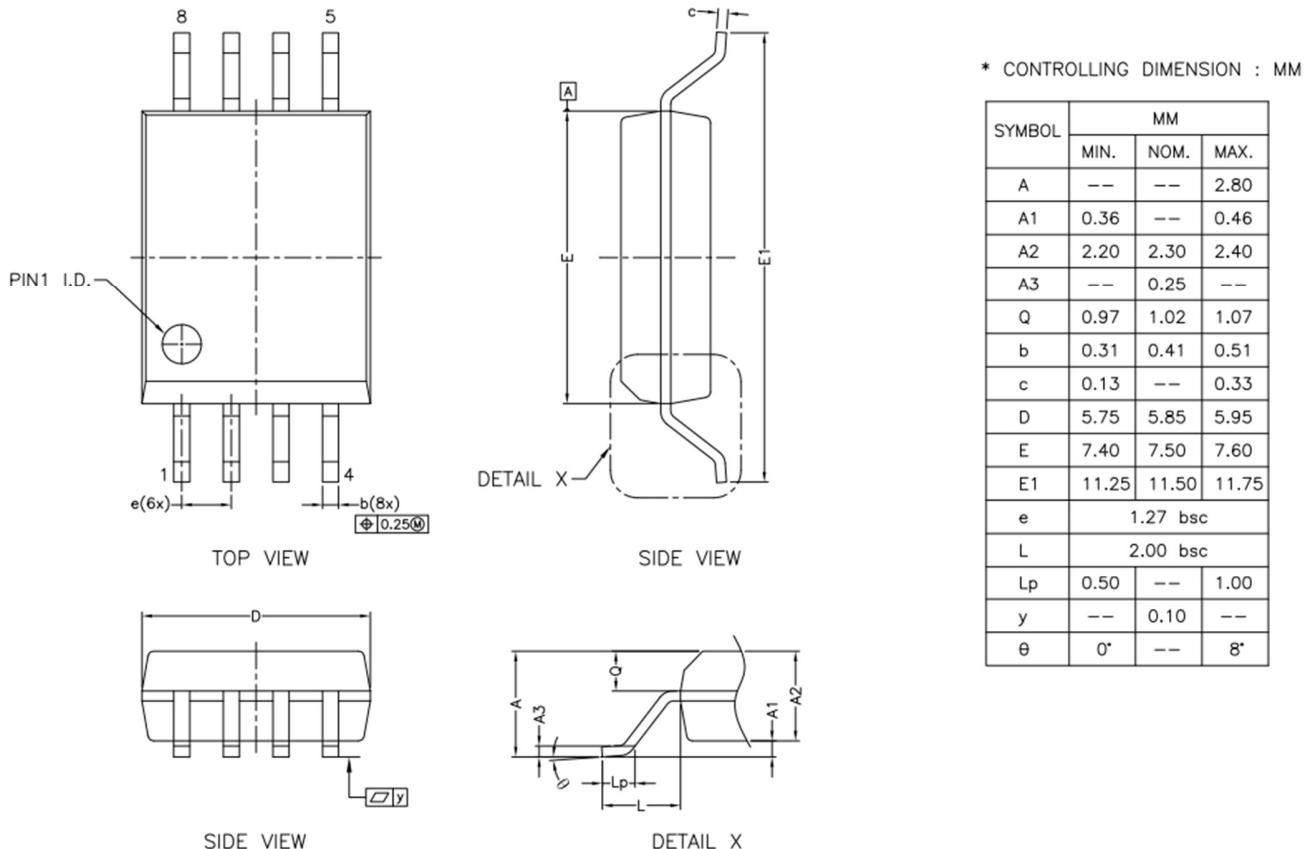
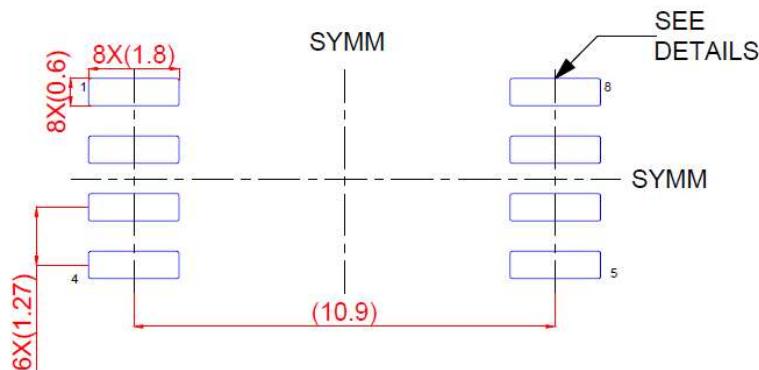


Figure 10.1 SOW8 Package Shape and Dimension in millimeters

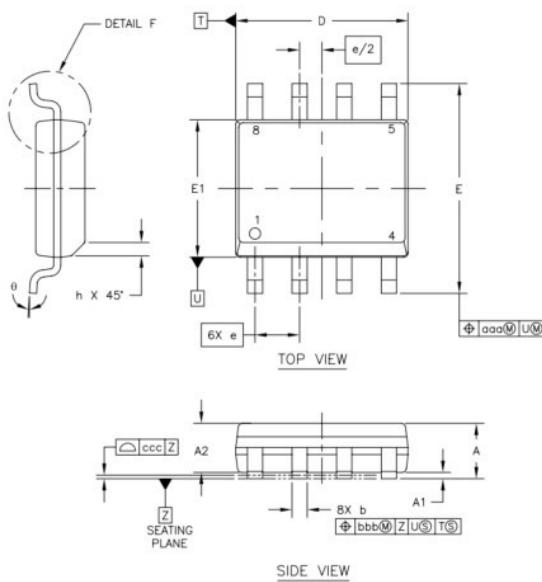


LAND PATTERN EXAMPLE(mm)  
9.1 mm NOMINAL  
CLEARANCE/CREEPAGE



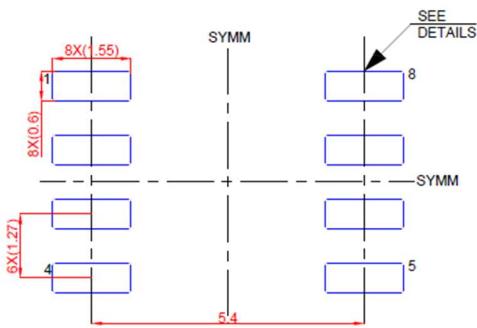
#### SOLDER MASK DETAILS

Figure 10.2 SOW8 Package Board Layout Example

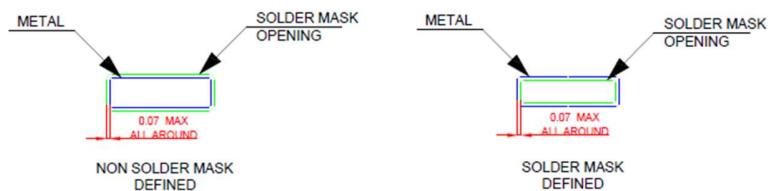


DESCRIPTION	SYMBOL	INCH			MILLIMETER		
		MIN	NOM	MAX	MIN	NOM	MAX
TOTAL THICKNESS	A	.053		.069	1.35		1.75
STAND OFF	A1	.004		.010	0.10		0.25
MOLD THICKNESS	A2	.049		---	1.25		---
LEAD WIDTH	b	.014		.019	0.35		0.49
L/F THICKNESS	c	.007		.010	0.19		0.25
BODY SIZE	D	.189		.197	4.80		5.00
	E1	.150		.157	3.80		4.00
	E	.228		.244	5.80		6.20
LEAD PITCH	e	.050 BSC			1.27 BSC		
	L	.016		.049	0.40		1.25
	h	.010		.020	0.25		0.50
	θ	0°		7°	0°		7°
	θ1	5°		15°	5°		15°
	θ2	2°	7°	12°	2°	7°	12°
LEAD EDGE OFFSET	aaa			.010			0.25
LEAD OFFSET	bbb			.010			0.25
COPLANARITY	ccc			.004			0.10

Figure 10.3 SOP8 package shape and dimension in millimeters



LAND PATTERN EXAMPLE(mm)



## SOLDER MASK DETAILS

Figure 10.4 SOP8 Package Board Layout Example

**11. Ordering Information**

Part No.	Isolation Rating(kV)	Linear Input Range(mV)	Moisture Sensitivity Level	Temperature	Automotive	Package Type	Package Drawing	SPQ
NSI1400D-DSWVR	5	-250 ~ 250	Level-3	-40 to 125°C	NO	SOP8 (300mil)	SOW8	1000
NSI1400D - DSPR	3	-250 ~ 250	Level-3	-40 to 125°C	NO	SOP8 (150mil)	SOP8	2500

**12. Documentation Support**

Part Number	Product Folder	Datasheet	Technical Documents	Isolator selection guide
NSI1400	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

## 13. Tape and Reel Information

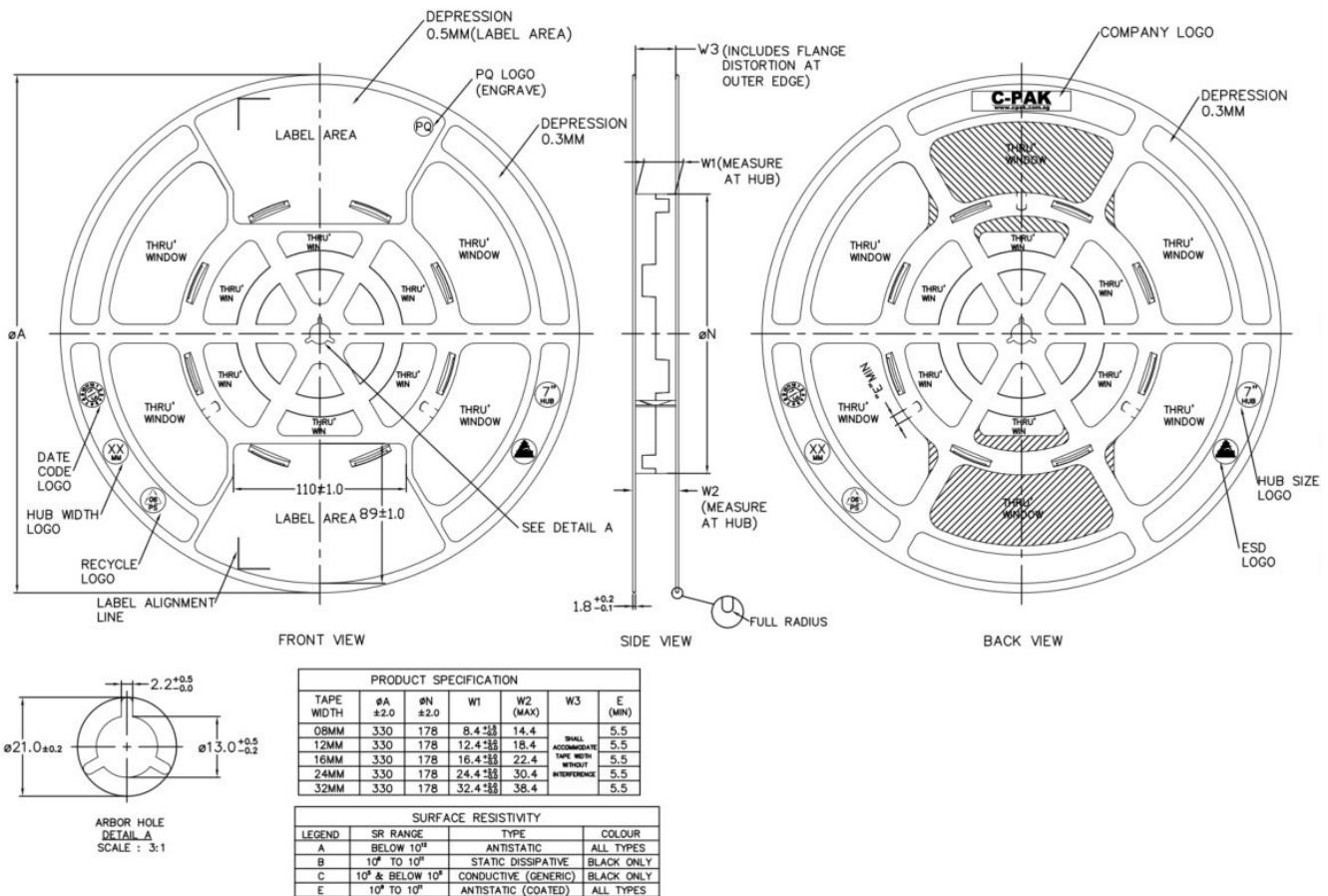


Figure 13.1 Tape Information

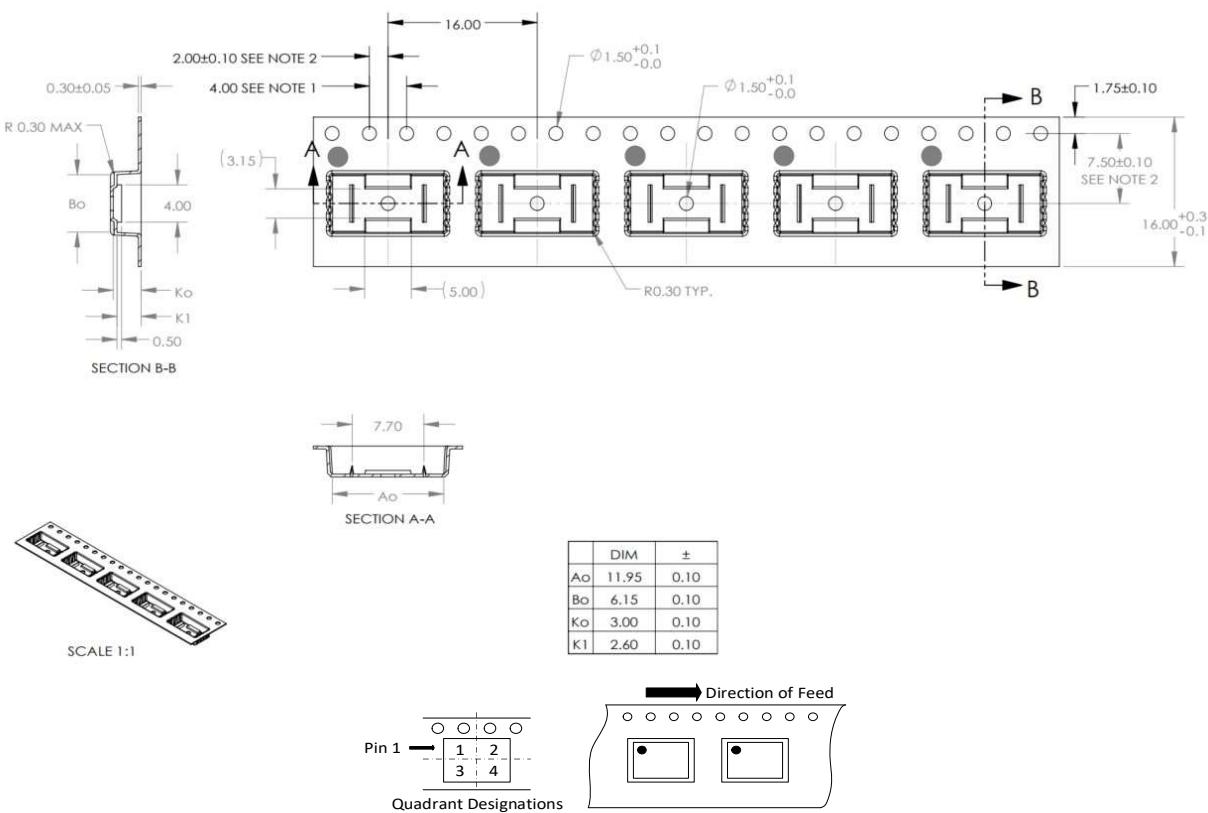


Figure 13.2 Reel Information of SOP8(300mil)

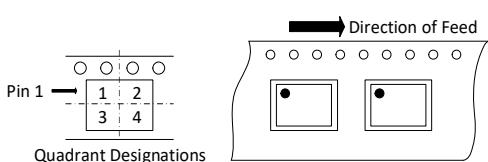
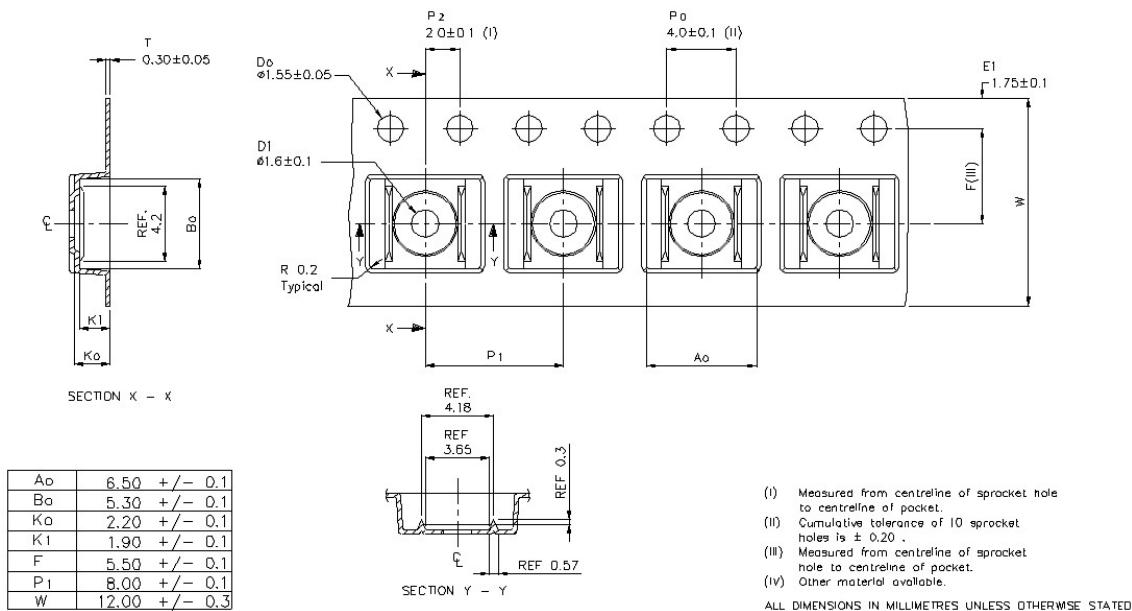


Figure 13.3 Reel Information of SOP8(150mil)

## 14. Revision History

Revision	Description	Date
1.0	Initial release	2023/10/31

## IMPORTANT NOTICE

The information given in this document shall in no event be regarded as any warranty or authorization of, express or implied, including but not limited to accuracy, completeness, merchantability, fitness for a particular purpose or infringement of any third party's intellectual property rights.

You are solely responsible for your use of Novosense' products and applications, and for the safety thereof. You shall comply with all laws, regulations and requirements related to Novosense's products and applications, although information or support related to any application may still be provided by Novosense.

The resources are intended only for skilled developers designing with Novosense' products. Novosense reserves the rights to make corrections, modifications, enhancements, improvements or other changes to the products and services provided. Novosense authorizes you to use these resources exclusively for the development of relevant applications designed to integrate Novosense's products. Using these resources for any other purpose, or any unauthorized reproduction or display of these resources is strictly prohibited. Novosense shall not be liable for any claims, damages, costs, losses or liabilities arising out of the use of these resources.

For further information on applications, products and technologies, please contact Novosense ([www.novosns.com](http://www.novosns.com)).

**Suzhou Novosense Microelectronics Co., Ltd**